Ordering number: EN4645

N-Channel Silicon MOSFET



2SK1890

## **Ultrahigh-Speed Switching Applications**

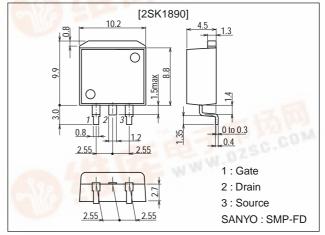
#### **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Surface mount type device making the following possible.
  - · Reduction in the number of manufacturing processes for 2SK1890-applied equipment.
- · High-density surface mount applications.
- · Small size of 2SK1890-applied equipment.

### **Package Dimensions**

unit:mm

2090A



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		30	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±20	V
Drain Current (DC)	I <sub>D</sub>	int.	22	А
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	88	Α
Allowable Power Dissipation	D-	- 1. July (1977)	1.65	W
	PD	Tc=25°C	60	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg	LINE MANUEL CO.	-55 to +150	°C

# Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	30			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I <sub>G</sub> =±100μA, V <sub>DS</sub> =0	±20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0		5	100	μΑ
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0	40.0	-11	±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0	L 07	2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =11A	9	15		S
Static Drain-to-Source ON-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =11A, V <sub>GS</sub> =10V		0.030	0.040	Ω
	R <sub>DS(on)</sub>	I <sub>D</sub> =11A, V <sub>GS</sub> =4V		0.040	0.055	Ω

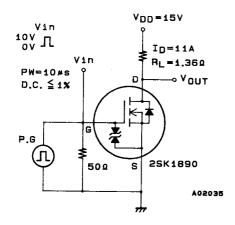
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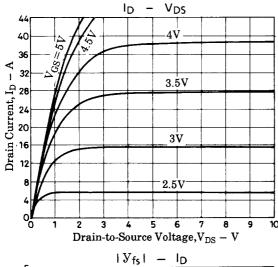
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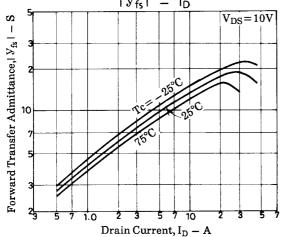
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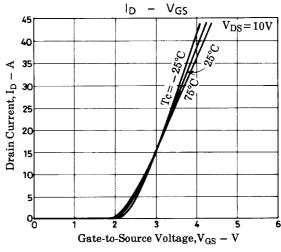
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		1300		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		720		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		240		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit		14		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		50		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>	See specified Test Circuit		290		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		150		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =22A, V <sub>GS</sub> =0		1.0	1.5	V

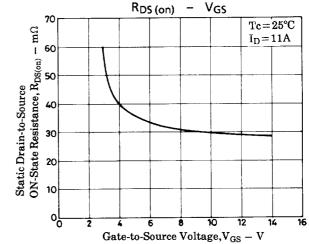
### **Switching Time Test Circuit**

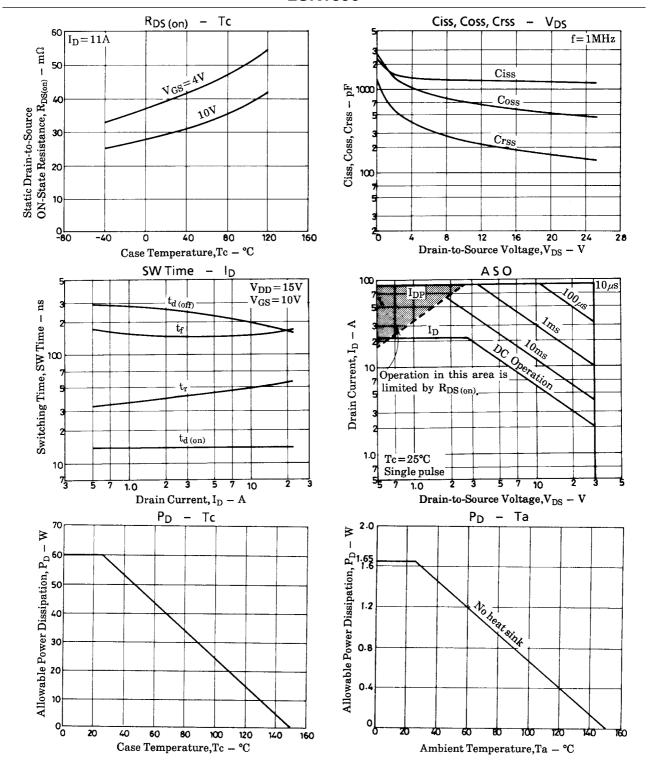












#### 2SK1890

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